74HC175; 74HCT175

Quad D-type flip-flop with reset; positive-edge trigger
Rev. 4 — 8 April 2014 Product of

Product data sheet

1. **General description**

The 74HC175; 74HCT175 are quad positive edge-triggered D-type flip-flops with individual data inputs (Dn) and both Qn and Qn outputs. The common clock (CP) and master reset (MR) inputs load and reset all flip-flops simultaneously. The D-input that meets the set-up and hold time requirements on the LOW-to-HIGH clock transition is stored in the flip-flop and appears at the Q output. A LOW on MR causes the flip-flops and outputs to be reset LOW.

The device is useful for applications where both the true and complement outputs are required and the clock and master reset are common to all storage elements.

Features and benefits 2.

- Input levels:
 - ◆ For 74HC175: CMOS level
 - ◆ For 74HCT175: TTL level
- Four edge-triggered D-type flip-flops
- Asynchronous master reset
- Complies with JEDEC standard no. 7A
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V.
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C.

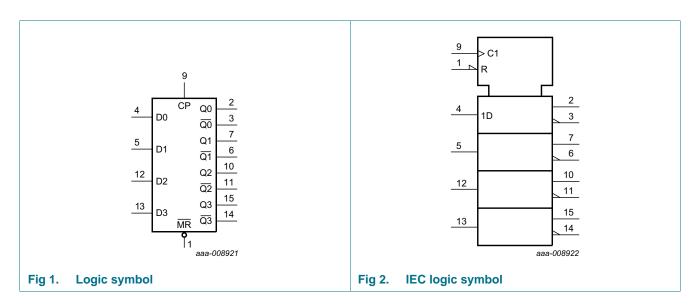
Ordering information

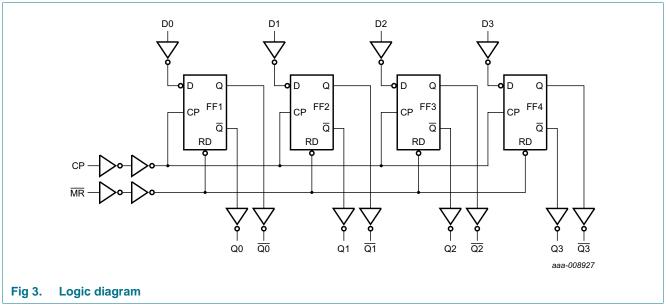
Table 1. **Ordering information**

Type number	Package	Package										
	Temperature range	Name	Description	Version								
74HC175N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4								
74HCT175N												
74HC175D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width	SOT109-1								
74HCT175D			3.9 mm									
74HC175DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1								
74HCT175DB			body width 5.3 mm									
74HC175PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1								
74HCT175PW			body width 4.4 mm									



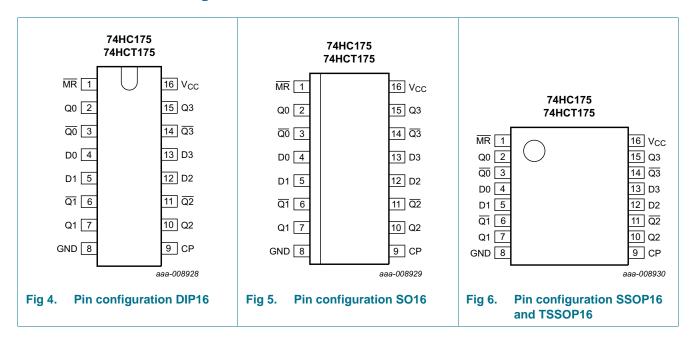
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
MR	1	asynchronous master reset input (active LOW)
Q0 to Q3	2, 7, 10, 15	flip-flop output
Q0 to Q3	3, 6, 11, 14	complementary flip-flop output
D0 to D3	4, 5, 12, 13	data input
GND	8	ground (0 V)
СР	9	clock input (LOW-to-HIGH edge-triggered)
V _{CC}	16	positive supply voltage

6. Functional description

Table 3. Function table[1]

Operating modes	Inputs			Outputs		
	MR	СР	Qn	Qn		
reset (clear)	L	Х	X	L	Н	
load "1"	Н	\uparrow	h	Н	L	
load "0"	Н	\uparrow	1	L	Н	

[1] H = HIGH voltage level;

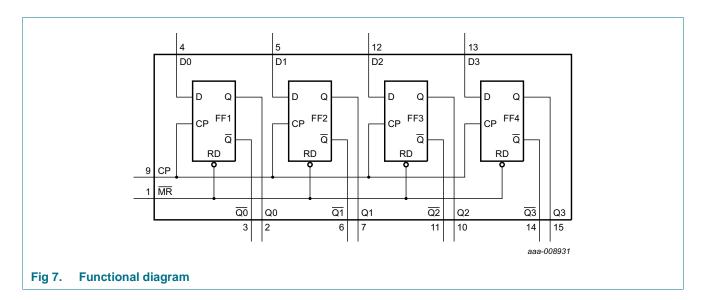
h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

↑ = LOW-to-HIGH clock transition.



7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C

Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$			
		DIP16 package [1]	-	750	mW
		SO16, SSOP16 and TSSOP16	-	500	mW

- [1] For DIP16 package: above 70 $^{\circ}$ C the value of P_{tot} derates linearly with 12 mW/K.
- [2] For SO16 package: above 70 $^{\circ}$ C the value of P_{tot} derates linearly with 8 mW/K. For SSOP16 and TSSOP16 packages: above 60 $^{\circ}$ C the value of P_{tot} derates linearly with 5.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC1	75		74HC	T175		Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	ns 25 °C		-40 °C	to +85 °C	-40 °C 1	o +125 °C	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
74HC17	5			'			'			
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL} LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V	
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 \text{ V}$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
l		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	75			'	'					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	8.0	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 5.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Δl _{CC}	additional supply current	per input pin; $V_{I} = V_{CC} - 2.1 \text{ V};$ other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$								
		Dn input	-	40	144	-	180	-	196	μΑ
		CP input	-	60	216	-	270	-	294	μΑ
		MR input	-	100	360	-	450	-	490	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit, see Figure 11

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC17	5									
t _{pd}	propagation delay	CP to Qn, Qn; see Figure 8	1							
		V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
[‡] PHL	HIGH to LOW propagation	MR to Qn, Qn; see Figure 10								
	delay	V _{CC} = 2.0 V	-	50	150	-	190	-	225	ns
		V _{CC} = 4.5 V	-	18	30	-	38	-	45	ns
		V _{CC} = 5 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	33	-	38	ns
t	transition time	Qn output; see Figure 8	1							
		V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
W	pulse width	CP input HIGH or LOW; see Figure 8								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		MR input LOW; see Figure 10								
		V _{CC} = 2.0 V	80	19	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
rec	recovery time	MR to CP; see Figure 10								
		V _{CC} = 2.0 V	5	-33	-	5	-	5	-	ns
		V _{CC} = 4.5 V	5	-12	-	5	-	5	-	ns
		V _{CC} = 6.0 V	5	-10	-	5	-	5	-	ns
su	set-up time	Dn to CP; see Figure 8								
		V _{CC} = 2.0 V	80	3	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	1	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	1	-	17	-	20	-	ns

 Table 7.
 Dynamic characteristics ...continued

GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit, see Figure 11

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _h	hold time	Dn to CP; see Figure 8								
		V _{CC} = 2.0 V	25	2	-	30	-	40	-	ns
		V _{CC} = 4.5 V	5	0	-	6	-	8	-	ns
		V _{CC} = 6.0 V	4	0	-	5	-	7	-	ns
f _{max}	maximum	CP input; see Figure 8								
	frequency	V _{CC} = 2.0 V	6	25	-	4.8	-	4	-	MHz
		V _{CC} = 4.5 V	30	75	-	24	-	20	-	MHz
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	83	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	89	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	per package; $V_I = GND$ to V_{CC}	-	32	-	-	-	-	-	pF
74HCT17	75							1		
t _{pd}	propagation delay	CP to Qn, Qn; see Figure 8								
		$V_{CC} = 4.5 \text{ V}$	-	19	33	-	41	-	50	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	16	-	-	-	-	-	ns
t _{PHL}	HIGH to LOW	MR to Qn; see Figure 10								
	propagation delay	$V_{CC} = 4.5 \text{ V}$	-	22	38	-	48	-	57	ns
	dolay	$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	19	-	-	-	-	-	ns
		MR to Qn; see Figure 10								
		$V_{CC} = 4.5 \text{ V}$	-	19	35	-	44	-	53	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	16	-	-	-	-	-	ns
t _t	transition time	Qn output; see Figure 8 [2]								
		$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns
t_{VV}	pulse width	CP input; see Figure 8								
		$V_{CC} = 4.5 \text{ V}$	20	12	-	25	-	30	-	ns
		MR input LOW; see Figure 10								
		$V_{CC} = 4.5 \text{ V}$	20	11	-	25	-	30	-	ns
t _{rec}	recovery time	MR to CP; see Figure 10								
		V _{CC} = 4.5 V	5	-10	-	5	-	5	-	ns
t _{su}	set-up time	Dn to CP; see Figure 8								
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
t _h	hold time	Dn to CP; see Figure 8								
		V _{CC} = 4.5 V	5	0	-	5	-	5	-	ns

Table 7. Dynamic characteristics ... continued

GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit, see Figure 11

Symbol	Parameter Conditions 25 °C			-40 °C to	o +85 °C	-40 °C to +125 °C		Unit			
				Min	Тур	Max	Min	Max	Min	Max	
f _{max}	maximum	CP input; see Figure 8									
	frequency	V _{CC} = 4.5 V		25	49	-	20	-	17	-	MHz
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	54	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	per package; V _I = GND to V _{CC} – 1.5 V	[3]	-	34	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [2] t_t is the same as t_{THL} and t_{TLH} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs};$

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V.

11. Waveforms

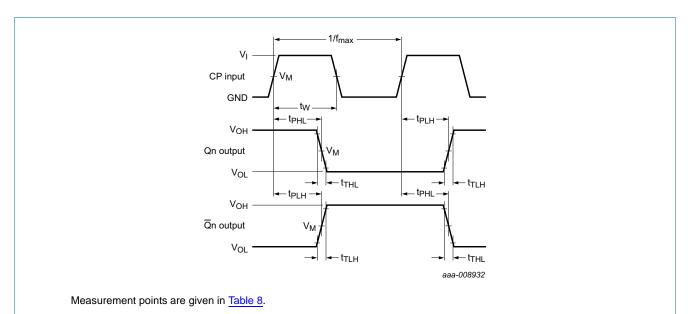
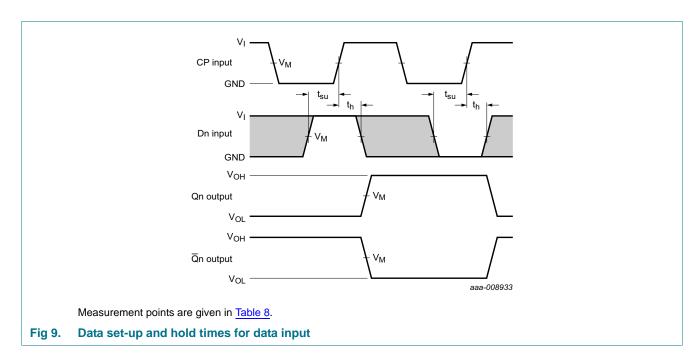
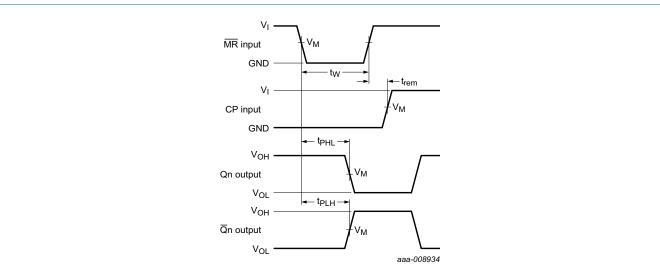


Fig 8. Input to output propagation delay, output transition time, clock input pulse width and maximum frequency



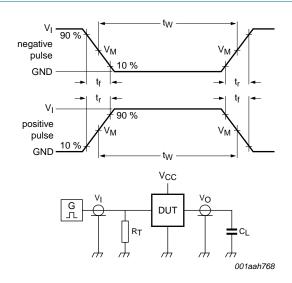


Measurement points are given in Table 8.

Fig 10. Master reset to output propagation delays, master reset pulse width and master reset to clock recovery time

Table 8. Measurement points

Туре	Input	Output	
	VI	V _M	
74HC175	V _{CC}	0.5V _{CC}	0.5V _{CC}
74HCT175	3 V	1.3 V	1.3 V



Test data is given in Table 9.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

Fig 11. Test circuit for measuring switching times

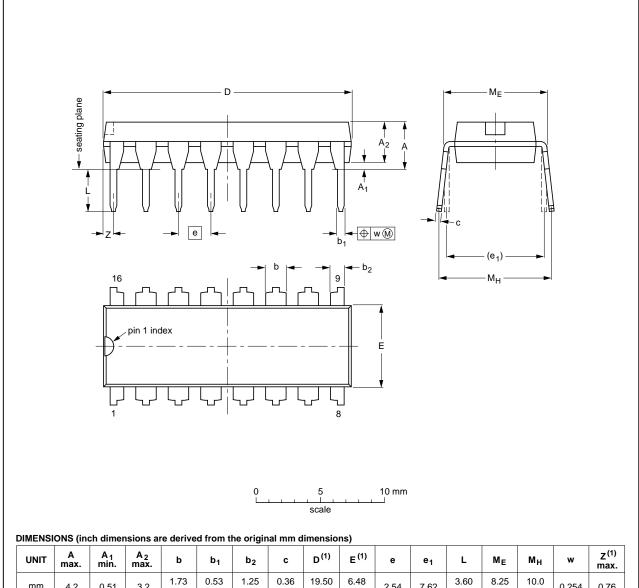
Table 9. Test data

Туре	Input		Load	Test	
	V _I	t _r , t _f	C _L	R _L	
74HC175	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	t _{PLH} , t _{PHL}
74HCT175	3 V	6 ns	15 pF, 50 pF	1 kΩ	t _{PLH} , t _{PHL}

12. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT38-4						95-01-14 03-02-13

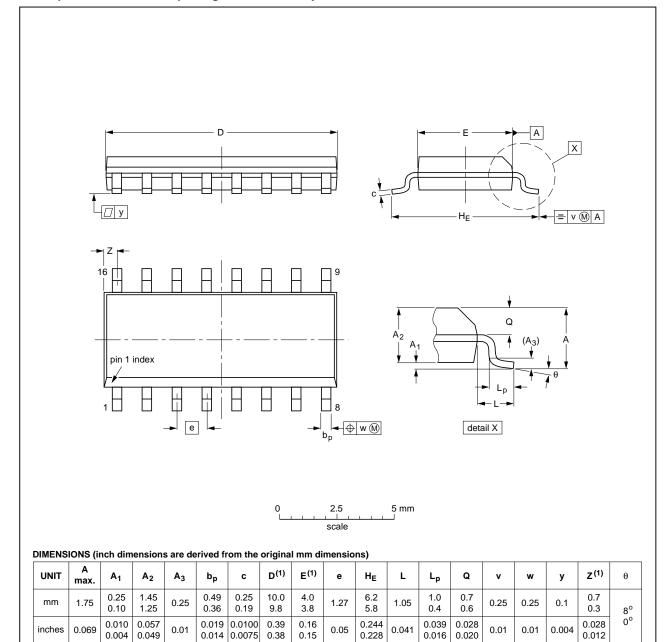
Fig 12. Package outline SOT38-4 (DIP16)

74HC_HCT175

All information provided in this document is subject to legal disclaimers.

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			99-12-27 03-02-19

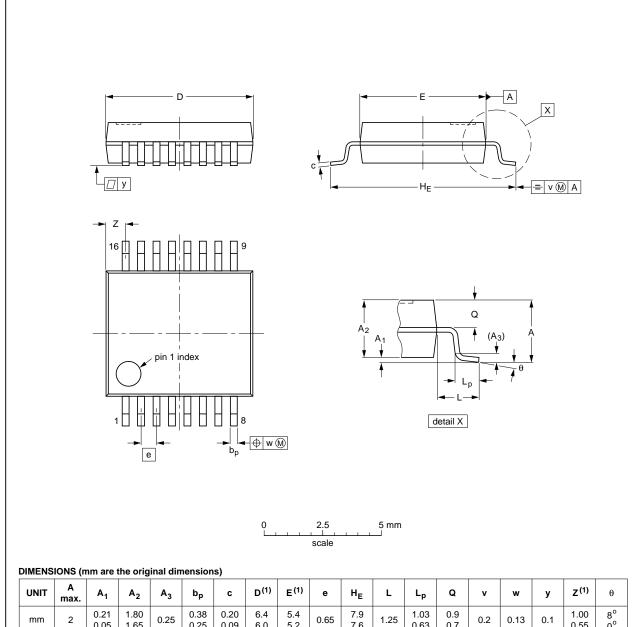
Fig 13. Package outline SOT109-1 (SO16)

74HC_HCT175

All information provided in this document is subject to legal disclaimers.

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ	
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°	

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT338-1		MO-150				99-12-27 03-02-19

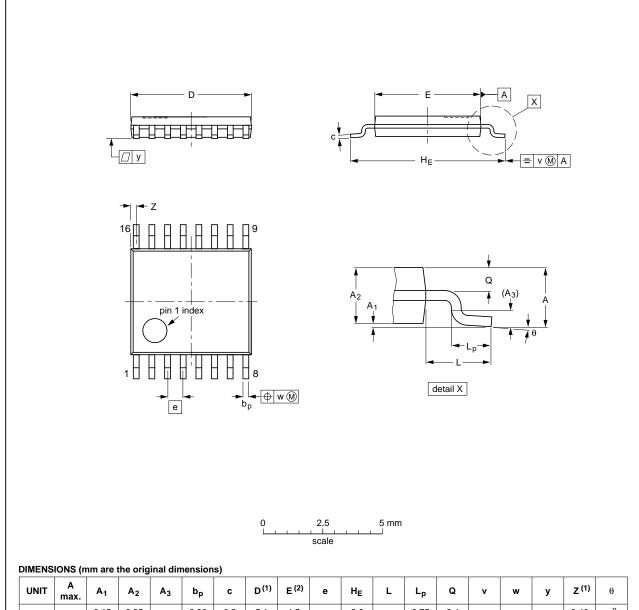
Fig 14. Package outline SOT338-1 (SSOP16)

74HC_HCT175

All information provided in this document is subject to legal disclaimers.

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT403-1		MO-153			99-12-27 03-02-18

Fig 15. Package outline SOT403-1 (TSSOP16)

74HC_HCT175

All information provided in this document is subject to legal disclaimers.

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT175 v.4	20140408	Product data sheet	-	74HC_HCT175 v.3
Modifications:	General desc	ription corrected (errata).		
74HC_HCT175 v.3	20140331	Product data sheet	-	74HC_HCT175_CNV_2
Modifications:		this data sheet has been rede	signed to comply wi	th the new identity
	 Legal texts ha 	ave been adapted to the new c	ompany name wher	e appropriate.
74HC_HCT175_CNV_2	19980708	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

15.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

74HC HCT175

All information provided in this document is subject to legal disclaimers.

74HC175; 74HCT175

Quad D-type flip-flop with reset; positive-edge trigger

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

16. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

17. Contents

1	General description
2	Features and benefits
3	Ordering information 1
4	Functional diagram 2
5	Pinning information 3
5.1	Pinning
5.2	Pin description
6	Functional description 4
7	Limiting values 4
8	Recommended operating conditions 5
9	Static characteristics 5
10	Dynamic characteristics
11	Waveforms
12	Package outline
13	Abbreviations
14	Revision history
15	Legal information
15.1	Data sheet status 17
15.2	Definitions
15.3	Disclaimers
15.4	Trademarks
16	Contact information
17	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.